## NSN 5961-01-169-3590

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View Online at https://aerobasegroup.com/nsn/5961-01-169-3590 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.340 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 nonrepetitive peak reverse voltage and 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 3.20 amperes forward current, total rms universal and 5.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector not applicable **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 89954-44a359491 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

**Fiig:** A110a0

No